

Vishay Siliconix

COMPLIANT

P-Channel 40-V (D-S) MOSFET

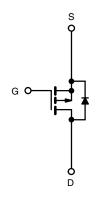
PRODUCT SUMMARY				
V _{DS} (V)	r _{DS(on)} (Ω)	I _D (A) ^a	Q _g (Typ.)	
- 40	0.040 at V _{GS} = - 10 V	- 8	17 nC	
- 40	0.050 at V _{GS} = - 4.5 V	- 8	17 110	

FEATURES

- TrenchFET[®] Power MOSFET
- 100 % UIS Tested

APPLICATIONS

- Backlight Inverter for LCD Display
- Full Bridge DC/DC Converter



TO-252

Top View

Ordering Information: SUD50P04-40P-E3 (Lead (Pb)-free)



ABSOLUTE MAXIMUM RATINGS	T _A = 25 °C, unles	s otherwise no	oted	
Parameter		Symbol	Limit	Unit
Drain-Source Voltage		V _{DS}	- 40	V
Gate-Source Voltage		V _{GS}	± 20	l v
Continuous Drain Current (T _J = 150 °C)	$T_{C} = 25 \text{ °C}$ $T_{C} = 70 \text{ °C}$ $T_{A} = 25 \text{ °C}$ $T_{A} = 70 \text{ °C}$	I _D	- 8 ^a - 8 ^a - 6 ^b - 4.8 ^b - 30	- A
Pulsed Drain Current		IDM		-
Continuous Source-Drain Diode Current	T _C = 25 °C T _A = 25 °C	I _S	- 8 ^a - 2.0 ^b	-
Single Pulse Avalanche Current	L = 0.1 mH	I _{AS}	15	
Avalanche Energy		E _{AS}	11.25	mJ
	T _C = 25 °C		24	
Maximum Power Dissipation	T _C = 70 °C	PD	15.3	w
	T _A = 25 °C T _A = 70 °C		2.4 ^b 1.5 ^b	-
Operating Junction and Storage Temperature Range		T _J , T _{stg}	- 55 to 150	°C

THERMAL RESISTANCE RATINGS					
Parameter		Symbol	Typical	Maximum	Unit
Maximum Junction-to-Ambient ^b	Steady State	R _{thJA}	43	52	°C/W
Maximum Junction-to-Case	Steady State	R _{thJC}	4.3	5.2	0/10

Notes:

a. Package limited.

b. Surface mounted on 1" x 1" FR4 board.



Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit	
Static	Cymbel			.,,,,,,	maxi		
Drain-Source Breakdown Voltage	V _{DS}	V _{GS} = 0 V, I _D = - 250 μA	- 40			V	
V _{DS} Temperature Coefficient	$\Delta V_{DS}/T_{J}$			- 41		mV/°C	
V _{GS(th)} Temperature Coefficient	$\Delta V_{GS(th)}/T_J$	I _D = - 250 μA		4.3			
Gate-Source Threshold Voltage	V _{GS(th)}	$V_{DS} = V_{GS}, I_{D} = -250 \ \mu A$	- 1.4		- 2.7	V	
Gate-Source Leakage	I _{GSS}	$V_{DS} = 0 V, V_{GS} = \pm 20 V$			± 100	nA	
	-635	$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}$			- 1		
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -40 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 70 \text{ °C}$			- 20	μΑ	
On-State Drain Current ^a	I _{D(on)}	$V_{DS} \ge -5 V, V_{GS} = -10 V$	- 10			Α	
	D(OII)	$V_{GS} = -10 \text{ V}, \text{ I}_{D} = -5 \text{ A}$		0.030	0.040	Ω	
Drain-Source On-State Resistance ^a	r _{DS(on)}	$V_{GS} = -4.5 \text{ V}, I_D = -4 \text{ A}$		0.036	0.050		
Forward Transconductance ^a	9 _{fs}	V _{DS} = - 15 V, I _D = - 5 A		20	1	S	
Dynamic ^b							
Input Capacitance	C _{iss}			1555			
Output Capacitance	C _{oss}	V _{DS} = - 20 V, V _{GS} = 0 V, f = 1 MHz		176		pF	
Reverse Transfer Capacitance	C _{rss}			142			
Takal Oaka Okarra		$V_{DS} = -20 \text{ V}, V_{GS} = -10 \text{ V}, I_{D} = -5 \text{ A}$		38.5	60	nC	
Total Gate Charge				17	27		
Gate-Source Charge	Q _{qs}	$V_{DS} = -20 V$, $V_{GS} = -4.5 V$, $I_{D} = -5 A$		4.2			
Gate-Drain Charge	Q _{qd}			7.0			
Gate Resistance	R _q	f = 1 MHz		3		Ω	
Turn-On Delay Time	t _{d(on)}			47	80		
Rise Time	t _r	$V_{DD} = -20 \text{ V}, \text{ R}_{1} = 4 \Omega$		60	110		
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -5 \text{ A}, V_{GEN} = -4.5 \text{ V}, R_g = 1 \Omega$		35	60		
Fall Time	t _f			13	25	1	
Turn-On Delay Time	t _{d(on)}			10	20	ns	
Rise Time	t _r	$V_{DD} = -20 \text{ V}, \text{ R}_{1} = 4 \Omega$		14	25	-	
Turn-Off Delay Time	t _{d(off)}	$I_D \cong -5 \text{ A}, V_{GEN} = -10 \text{ V}, R_g = 1 \Omega$		36	60		
Fall Time	t _f			10	20		
Drain-Source Body Diode Characteris	tics	· · · · · · · · · · · · · · · · · · ·		·			
Continuous Source-Drain Diode Current	ا _S	T _C = 25 °C			- 8	۸	
Pulse Diode Forward Current ^a	I _{SM}				- 30	A	
Body Diode Voltage	V _{SD}	I _S = - 2 A		- 0.76	- 1.2	V	
Body Diode Reverse Recovery Time	t _{rr}			22	40	ns	
Body Diode Reverse Recovery Charge	Q _{rr}			22	40	nC	
Reverse Recovery Fall Time	t _a	$I_F = 20 \text{ A}, \text{ di/dt} = 100 \text{ A/}\mu\text{s}, T_J = 25 ^\circ\text{C}$		15			
Reverse Recovery Rise Time	t _b			7		ns	

Notes:

a. Pulse test; pulse width \leq 300 $\mu s,$ duty cycle \leq 2 %.

b. Guaranteed by design, not subject to production testing.

Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.



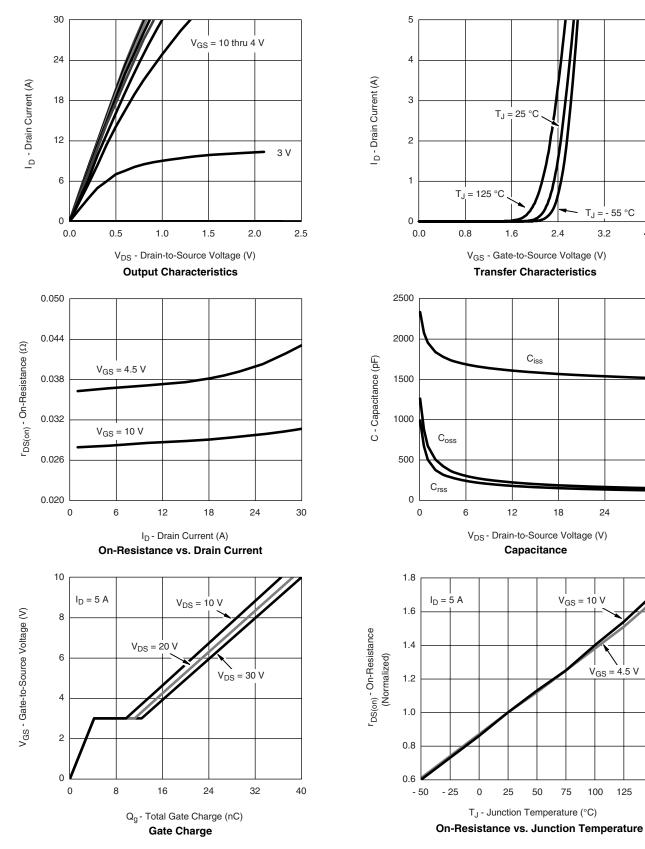


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4.0

30

TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Document Number: 69731 S-80109-Rev. B, 21-Jan-08 125

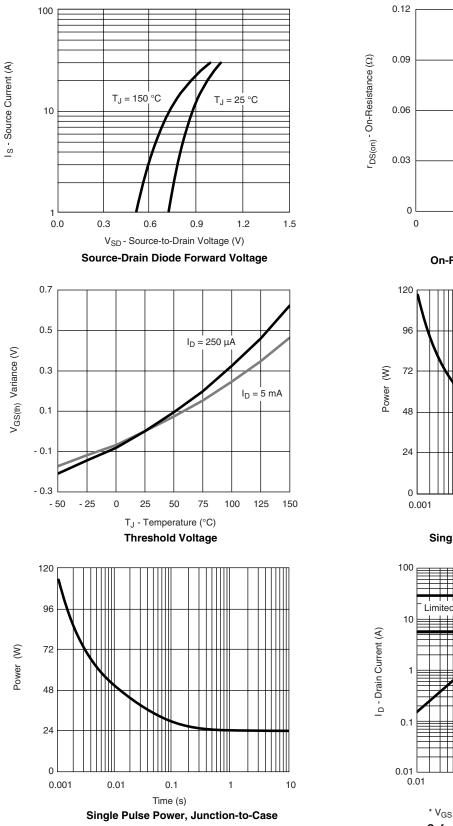
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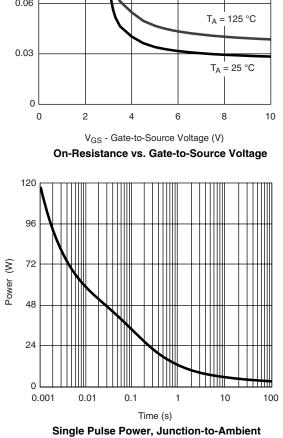
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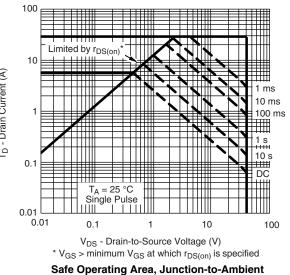
 $I_D = 5 A$

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted

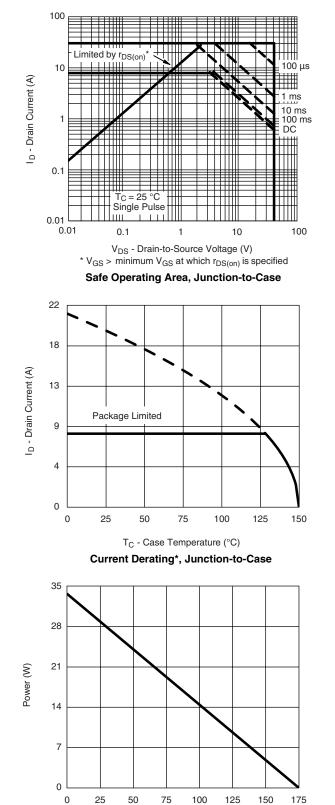




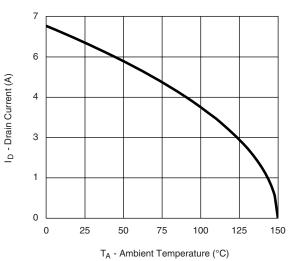




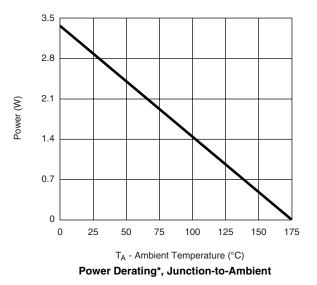




T_C - Case Temperature (°C) Power Derating*, Junction-to-Case



Current Derating*, Junction-to-Ambient

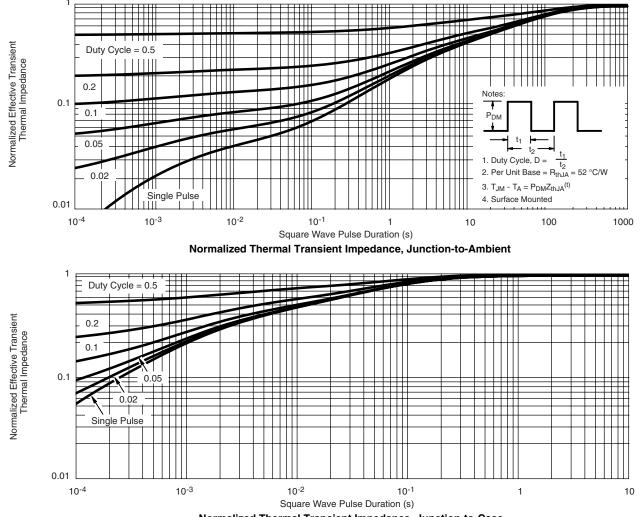


* The power dissipation P_D is based on T_{J(max)} = 175 °C, using junction-to-case thermal resistance, and is more useful in settling the upper dissipation limit for cases where additional heatsinking is used. It is used to determine the current rating, when this rating falls below the package limit.

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TYPICAL CHARACTERISTICS 25 °C, unless otherwise noted



Normalized Thermal Transient Impedance, Junction-to-Case

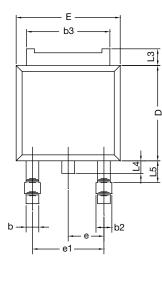
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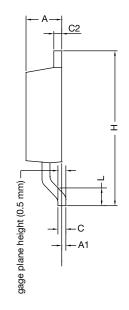




TO-252AA Case Outline

VERSION 1: FACILITY CODE = Y







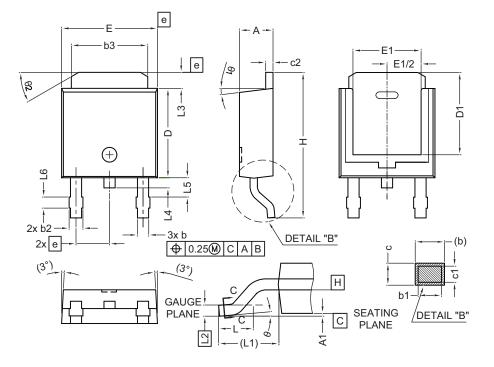
	MILLIMETERS		
DIM.	MIN.	MAX.	
А	2.18	2.38	
A1	-	0.127	
b	0.64	0.88	
b2	0.76	1.14	
b3	4.95	5.46	
С	0.46	0.61	
C2	0.46	0.89	
D	5.97	6.22	
D1	4.10	-	
E	6.35	6.73	
E1	4.32	-	
Н	9.40	10.41	
е	2.28 BSC		
e1	4.56 BSC		
L	1.40	1.78	
L3	0.89	1.27	
L4	-	1.02	
L5	1.01	1.52	

Note

• Dimension L3 is for reference only



VERSION 2: FACILITY CODE = N



	MILLIMETERS		
DIM.	MIN.	MAX.	
A	2.18	2.39	
A1	-	0.13	
b	0.65	0.89	
b1	0.64	0.79	
b2	0.76	1.13	
b3	4.95	5.46	
с	0.46	0.61	
c1	0.41	0.56	
c2	0.46	0.60	
D	5.97	6.22	
D1	5.21	-	
E	6.35	6.73	
E1	4.32 -		
e	2.29 BSC		
Н	9.94	10.34	

	MILLIMETERS		
DIM.	MIN.	MAX.	
L	1.50	1.78	
L1	2.74 ref.		
L2	0.51 BSC		
L3	0.89	1.27	
L4	-	1.02	
L5	1.14	1.49	
L6	0.65	0.85	
θ	0°	10°	
θ1	0°	15°	
θ2	25°	35°	

Notes

Dimensioning and tolerance confirm to ASME Y14.5M-1994

All dimensions are in millimeters. Angles are in degrees

Heat sink side flash is max. 0.8 mm

Radius on terminal is optional ٠

ECN: E19-0649-Rev. Q, 16-Dec-2019 DWG: 5347



RECOMMENDED MINIMUM PADS FOR DPAK (TO-252)



Recommended Minimum Pads Dimensions in Inches/(mm)

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